

# **DEPARTMENT OF ELECTRONICS & COMMUNICATION ENGINEERING**



**THAPAR INSTITUTE**  
OF ENGINEERING & TECHNOLOGY  
(Deemed to be University)

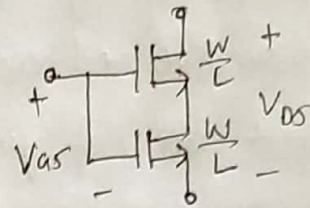
## **Analog IC Design Assignment-1**

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## Assignment-1

① Based on Problem 2.16 of the Razavi's book:

Consider the structure shown in the following figure. Determine  $I_D$  as a function of  $V_{GS}$  and  $V_{DS}$  and prove that the structure can be viewed as a single transistor having an aspect ratio  $W/(2L)$ . Assume  $\lambda = \gamma = 0$



case-1  $M_1$ : Triode,  $M_2$ : Triode

$$V_{DD1} = V_{GS} - V_{th},$$

$$V_{DD2} = V_{GS} - V_x - V_{th}$$

$$V_{DS1} = V_x, \quad V_{DS2} = V_{DS} - V_x$$

$$I_{D1} = \frac{1}{2} \mu_n C_{ox} \frac{W}{L} [2(V_{GS} - V_{th})V_x - V_x^2] \quad \text{--- ①}$$

$$I_{D2} = \frac{1}{2} \mu_n C_{ox} \frac{W}{L} [2(V_{GS} - V_{th} - V_x)(V_{DS} - V_x) - (V_{DS} - V_x)^2]$$

$$I_{D1} = I_{D2}$$

$$2(V_{GS} - V_{th})V_x - V_x^2 = 2(V_{GS} - V_{th})V_{DS} + 2V_x^2 - 2V_x(V_{GS} - V_{th}) - 2(V_x V_{DS}) - V_{DS}^2 - V_x^2 + 2V_x V_{DS}$$

$$= 2[2(V_{GS} - V_{th})V_x - V_x^2] = 2(V_{GS} - V_{th})V_{DS} - V_{DS}^2 \quad \text{--- ②}$$

from eq ① & ②

$$I_{D1} = I_{D2} = \frac{1}{2} \mu_n C_{ox} \frac{W}{L} \times \frac{1}{2} [2(V_{GS} - V_{th})V_{DS} - V_{DS}^2] \Rightarrow \frac{W}{2L} \text{ is in triode}$$

case-2  $M_1$ : Triode,  $M_2$ : saturation

$$I_{D1} = \frac{1}{2} \mu_n C_{ox} \frac{W}{L} [2(V_{GS} - V_{th})V_x - V_x^2] \quad \text{--- ③}$$

$$I_{D2} = \frac{1}{2} \mu_n C_{ox} \frac{W}{L} (V_{GS} - V_x - V_{th})^2$$

$$I_{D1} = I_{D2}$$

$$V_x^2 - 2V_x(V_{GS} - V_{th}) + (V_{GS} - V_{th})^2 = 2(V_{GS} - V_{th})V_x - V_x^2$$

$$(V_{GS} - V_{th})^2 = 2[2(V_{GS} - V_{th})V_x - V_x^2] \quad \text{--- ④}$$

from eq ③ & ④

$$I_{D1} = I_{D2} = \frac{1}{2} \mu_n C_{ox} \frac{W}{L} \times \frac{1}{2} (V_{GS} - V_{th})^2 \Rightarrow \frac{W}{2L} \text{ is in saturation}$$

$$\text{as } V_{GS} - V_{th} \geq 0 \Rightarrow V_{GS} - V_x - V_{th} > 0 \Rightarrow V_{GS} - V_{th} > V_x$$

$$V_{GS1} - V_{th} > V_{DS1} \Rightarrow M_1 \text{ is in triode}$$

It means the equivalent transistor is in saturation, if  $M_2$  is in saturation and vice versa.

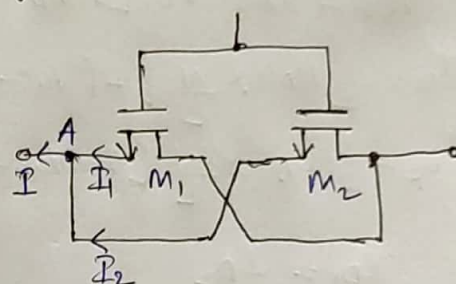
- ② Repeat part ① of question for the following structure (assuming both transistors have the same aspect ratio  $W/L$ ) and show that the structure can be viewed as a single transistor having an aspect ratio of  $2W/L$ .

At point A

$$I_{D1} + I_{D2} = I$$

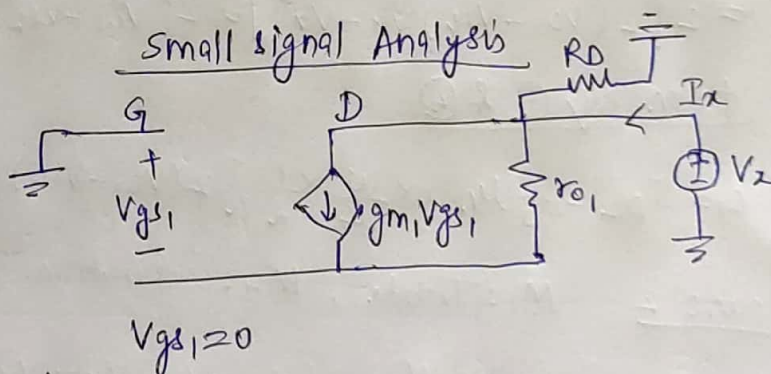
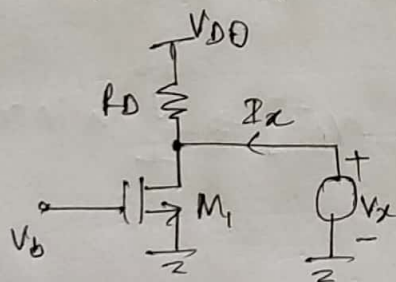
$$\Rightarrow \frac{1}{2} \mu_n C_{ox} \frac{2W}{L} (V_{GS} - V_{th})^2$$

$\Rightarrow$  which equals the transistors to be a single transistor of  $2W$  width.



- ③ Calculate the output resistance ( $V_x/I_x$ ) of following circuit. Assume  $\lambda \neq 0$  and  $r \neq 0$

①



Applying KCL in output node.

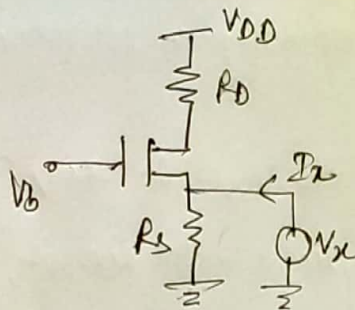
$$I_x = \frac{V_x}{r_{o1}} + \frac{V_x}{R_D}$$

$$\boxed{\frac{V_x}{I_x} = \frac{r_{o1} R_D}{r_{o1} + R_D}}$$

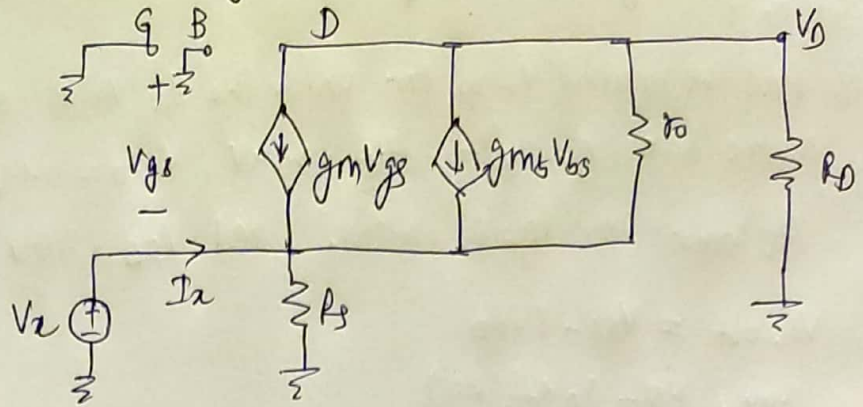
$$\text{or } \boxed{\frac{V_x}{I_x} = r_{o1} \parallel R_D}$$



⑥



Small signal Analysis



$$V_{gs} = -V_x$$

$$g_m V_{gs} = -g_m V_x$$

$$g_{mb} V_{bs} = g_{mb} (0 - V_x) = -g_{mb} V_x$$

Apply KCL at drain terminal:

$$\frac{V_D}{R_D} + \frac{V_D - V_x}{r_o} + g_m V_{gs} + g_{mb} V_{bs} = 0$$

$$\frac{V_D}{R_D} + \frac{V_D - V_x}{r_o} - g_m V_x - g_{mb} V_x = 0$$

$$V_D \left[ \frac{1}{R_D} + \frac{1}{r_o} \right] = V_x \left[ \frac{1}{r_o} + g_m + g_{mb} \right] \quad \text{--- (1)}$$

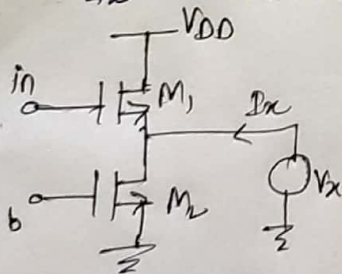
Apply KCL at source terminal

$$I_x = \frac{V_x}{R_S} + \frac{V_D}{R_D} = \frac{V_x}{R_S} + \frac{1}{R_D} \left[ \frac{\frac{1}{r_o} + g_m + g_{mb}}{\frac{1}{R_D} + \frac{1}{r_o}} \right] V_x$$

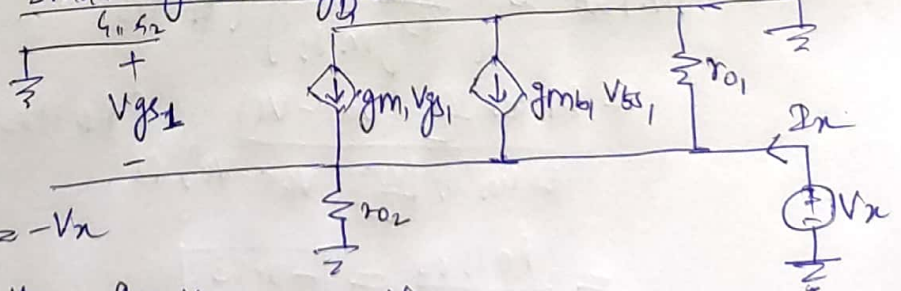
$$I_x = V_x \left[ \frac{1}{R_S} + \frac{\frac{1}{r_o} + g_m + g_{mb}}{1 + \frac{R_D}{r_o}} \right]$$

$$\frac{V_x}{I_x} = \frac{R_S R_D + R_S r_o}{r_o + R_D + R_S + (g_m + g_{mb}) r_o R_S}$$

⑦



small signal analysis



$$V_{gs1} = -V_x, \quad V_{bs1} = 0 - V_x = -V_x$$

KCL

$$I_x = \frac{V_x}{R_S} + \frac{V_x}{r_{o1}} - g_{m1} V_{gs1} - g_{mb1} V_{bs1}$$

$$= \frac{V_x}{R_S} + \frac{V_x}{r_{o1}} + g_{m1} V_x + g_{mb1} V_x$$

$$I_x = V_x \left[ \frac{1}{R_S} + \frac{1}{r_{o1}} + g_{m1} + g_{mb1} \right]$$

$$\boxed{\frac{V_x}{I_x} = \frac{1}{g_{m1} + g_{mb1} + \frac{1}{R_S} + \frac{1}{r_{o1}}}}$$

④ In the following ckt, assuming that the transistor is operating in saturation region:

① Find the required  $V_{bias}$  for which the dc value of the  $V_{out}$  is  $1.44V$

Assume  $\lambda = 0$ ,  $\eta = 1V^{1/2}$ ,  $2\phi_F = 0.64V$ ,  $V_{th0} = 0.4V$ ,  $\mu_n C_{ox} = 800 \mu A/V^2$ ,

$(\frac{W}{L})_{nmos} = 20$ ,  $R_D = R_S = 20.5 k\Omega$ , and  $V_{DD} = 1.8V$

$$V_{dc-out} = V_{dd} - I_D R_D$$

$$1.44 = 1.8 - I_D \times \left(\frac{1}{2} k\Omega\right)$$

$$I_D = (1.8 - 1.44) \text{ mA}$$

$$= 0.36 \times 2 = \boxed{0.72 \text{ mA}}$$

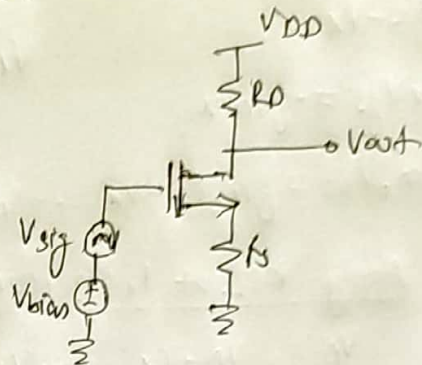
$$I_D = \frac{1}{2} \mu_n C_{ox} \frac{W}{L} (V_{GS} - V_{th})^2$$

$$V_{th} = V_{th0} + r(\sqrt{2\phi_F + V_{SB}} - \sqrt{2\phi_F}) = 0.6V$$

$$V_{GS} = V_{bias} - I_D R_D = V_{bias} - 0.36$$

$$0.72 \times 10^{-3} = \frac{1}{2} \mu_n C_{ox} \frac{W}{L} (V_{bias} - 0.36 - V_{th})^2$$

$$\boxed{V_{bias} = 1.26V}$$



② Is the assumption that the transistor is in saturation region?

$$V_{GS} = 1.26 - 1.44 < V_{th}$$

saturation

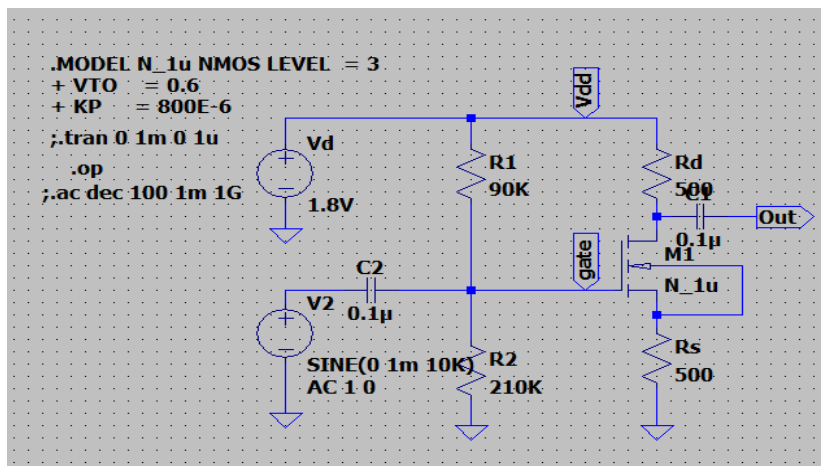
③ Find the small-signal gain  $V_{out}/V_{sig}$   
As  $G_m R_{out} \approx \left[ \frac{g_m}{1 + g_m R_S} \right] (R_D || R_o)$

$$= \frac{\mu_n C_{ox} \frac{W}{L} (V_{GS} - V_{th})}{1 + \mu_n C_{ox} \frac{W}{L} (V_{GS} - V_{th}) R_S} (R_D || R_o)$$

$$= \frac{R_D || R_o}{R_S} = \boxed{-0.53}$$

## Assignment-1(LTSPICE)

### Question-4 Diagram:



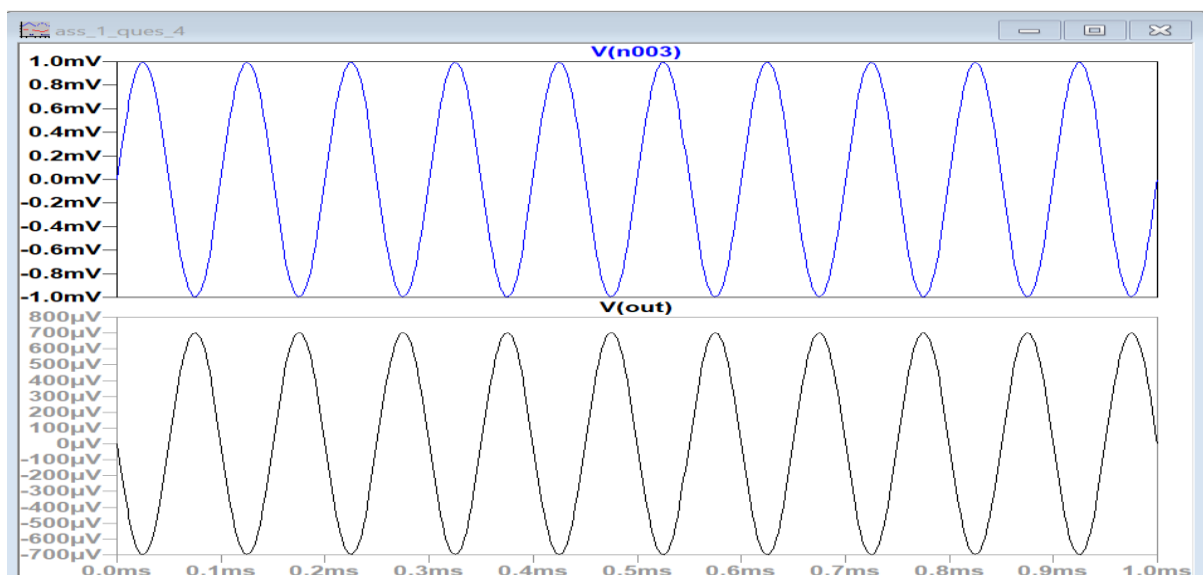
### DC Operating point Values:

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--- Operating Point ---

V(n001):	1.44	voltage
V(gate):	1.26	voltage
V(n002):	0.36	voltage
V(vdd):	1.8	voltage
V(n003):	0	voltage
V(out):	1.44e-007	voltage
Id(M1):	0.00072	device_current
Ig(M1):	0	device_current
Ib(M1):	-1.09e-012	device_current
Is(M1):	-0.00072	device_current
I(C2):	1.26e-019	device_current
I(C1):	-1.44e-019	device_current
I(R2):	6e-006	device_current
I(R1):	6e-006	device_current
I(Rs):	0.00072	device_current
I(Rd):	0.00072	device_current
I(V2):	1.26e-019	device_current
I(Vd):	-0.000726	device_current

### Transient Analysis:





## AC Analysis

